

## 3-TERMINAL NEGATIVE VOLTAGE REGULATOR

### ■ FEATURES

- Full Compatible with NJM79L00UA
- Output Current 100 mA
- Output Voltage Accuracy  $V_O \pm 4.0\%$
- Operating Temperature  $T_a = -40^\circ\text{C}$  to  $125^\circ\text{C}$
- High Ripple Rejection
- Overcurrent Protection
- Thermal Shutdown
- Bipolar Process
- Package SOT-89-3

### ■ APPLICATIONS

- Industrial Equipment
- OA Equipment
- Consumer Equipment

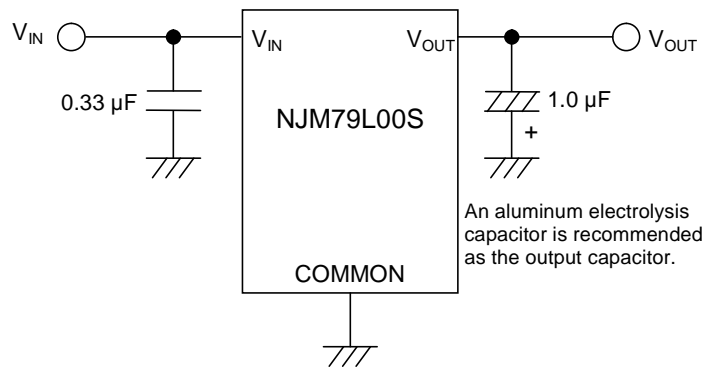
### ■ DESCRIPTION

The NJM79L00S series negative voltage regulators deliver up to 100 mA of output current.

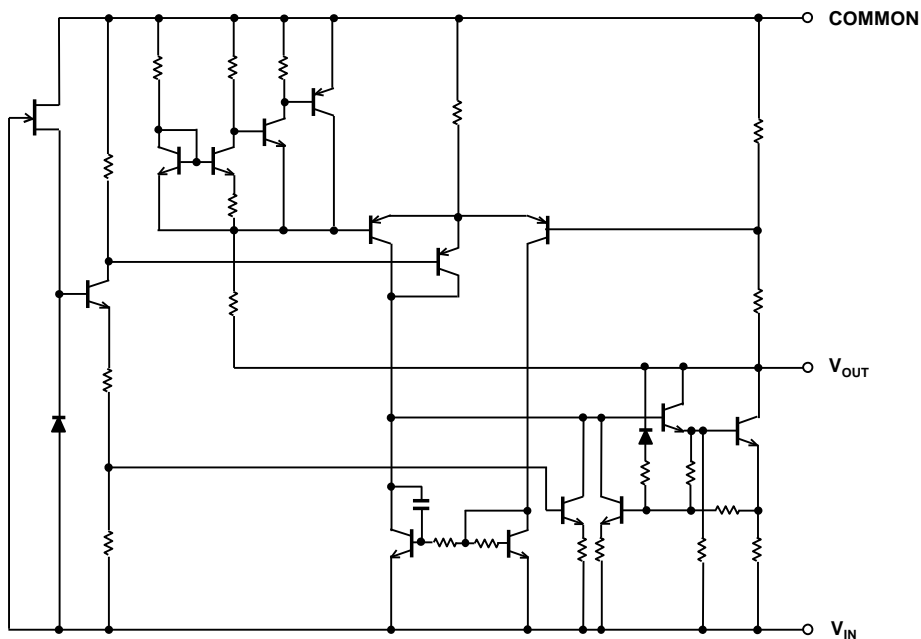
This series is enabling to direct replacement from NJM79L00UA series.

These devices offer improved usability by extending the operating temperature and maximum input voltage. This series is available in a SOT-89-3 package and is specified over the industrial temperature range of  $-40^\circ\text{C}$  to  $125^\circ\text{C}$ .




### ■ TYPICAL APPLICATION



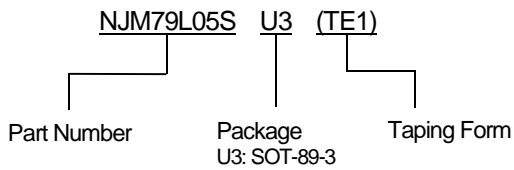
### ■ EQUIVALENT CIRCUIT



## ■ PIN CONFIGURATIONS

PIN FUNCTIONS	PIN NO.	SYMBOL	DESCRIPTION
COMMON 1 	1	COMMON	Common pin
$V_{IN}$ 2 	2	$V_{IN}$	Input pin
$V_{OUT}$ 3 	3	$V_{OUT}$	Output pin

## ■ PRODUCT NAME INFORMATION



## ■ ORDERING INFORMATION

PRODUCT NAME	OUTPUT VOLTAGE	PACKAGE	RoHS	HALOGEN-FREE	TERMINAL FINISH	MARKING	WEIGHT (mg)	MOQ (pcs)
NJM79L05SU3 (TE1)	-5.0 V	SOT-89-3	Yes	Yes	Sn-2Bi	111	61	1000
NJM79L06SU3 (TE1)	-6.0 V	SOT-89-3	Yes	Yes	Sn-2Bi	121	61	1000
NJM79L08SU3 (TE1)	-8.0 V	SOT-89-3	Yes	Yes	Sn-2Bi	131	61	1000
NJM79L09SU3 (TE1)	-9.0 V	SOT-89-3	Yes	Yes	Sn-2Bi	141	61	1000
NJM79L12SU3 (TE1)	-12 V	SOT-89-3	Yes	Yes	Sn-2Bi	151	61	1000
NJM79L15SU3 (TE1)	-15 V	SOT-89-3	Yes	Yes	Sn-2Bi	161	61	1000

## ■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Input Voltage	$V_{IN}$	+0.3 to -40	V
Output Voltage	$V_{OUT}$	+0.3 to $V_{IN}$ (-40) <sup>(1)</sup>	V
Power Dissipation ( $T_a = 25^\circ\text{C}$ ) SOT-89-3	$P_D$	2-Layer <sup>(2)</sup> / 4-Layer <sup>(3)</sup> 580 / 2200	mW
Junction Temperature	$T_J$	-40 to 150	$^\circ\text{C}$
Operating Temperature	$T_{opr}$	-40 to 125	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-50 to 150	$^\circ\text{C}$

(1) Although the terminal rating is -40 V, the output voltage must not exceed the input voltage.

(2) 2-Layer: Mounted on glass epoxy board (76.2 mm × 114.3 mm × 1.6 mm: based on EIA/JEDEC standard, 2-layer FR-4).

(3) 4-Layer: Mounted on glass epoxy board (76.2 mm × 114.3 mm × 1.6 mm: based on EIA/JEDEC standard, 4-layer FR-4).

(For 4-layer: Applying 74.2 mm × 74.2 mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5.)

## ■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Operating Voltage	$V_{IN}$	$V_O - 2.0$ to -30	V
Output Current	$I_O$	0 to 100	mA

## ■ ELECTRICAL CHARACTERISTICS

$C_{IN} = 0.33 \mu\text{F}$ ,  $C_O = 1.0 \mu\text{F}$ ,  $T_J = 25^\circ\text{C}$ , unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>NJM79L05S</b>						
Output Voltage	$V_O$	$V_{IN} = -10 \text{ V}$ , $I_O = 40 \text{ mA}$	-4.80	-5.00	-5.20	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -7 \text{ V to } -20 \text{ V}$ , $I_O = 40 \text{ mA}$	-	15	100	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -10 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	7	50	mV
Quiescent Current	$I_Q$	$V_{IN} = -10 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.0	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -8 \text{ V to } -18 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{PP}$ , $f = 120 \text{ Hz}$	41	76	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -10 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	110	-	$\mu\text{V}$
<b>NJM79L06S</b>						
Output Voltage	$V_O$	$V_{IN} = -12 \text{ V}$ , $I_O = 40 \text{ mA}$	-5.76	-6.00	-6.24	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -8.5 \text{ V to } -20 \text{ V}$ , $I_O = 40 \text{ mA}$	-	18	100	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -12 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	8	60	mV
Quiescent Current	$I_Q$	$V_{IN} = -12 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.0	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -9 \text{ V to } -19 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{PP}$ , $f = 120 \text{ Hz}$	40	71	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -12 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	140	-	$\mu\text{V}$
<b>NJU79L08S</b>						
Output Voltage	$V_O$	$V_{IN} = -14 \text{ V}$ , $I_O = 40 \text{ mA}$	-7.68	-8.00	-8.32	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -10.5 \text{ V to } -23 \text{ V}$ , $I_O = 40 \text{ mA}$	-	24	120	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -14 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	10	70	mV
Quiescent Current	$I_Q$	$V_{IN} = -14 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.0	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -11 \text{ V to } -21 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{PP}$ , $f = 120 \text{ Hz}$	39	69	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -14 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	190	-	$\mu\text{V}$
<b>NJM79L09S</b>						
Output Voltage	$V_O$	$V_{IN} = -15 \text{ V}$ , $I_O = 40 \text{ mA}$	-8.64	-9.00	-9.36	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -11.5 \text{ V to } -24 \text{ V}$ , $I_O = 40 \text{ mA}$	-	27	140	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -15 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	12	75	mV
Quiescent Current	$I_Q$	$V_{IN} = -15 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.0	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -12 \text{ V to } -22 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{PP}$ , $f = 120 \text{ Hz}$	38	68	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -15 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	210	-	$\mu\text{V}$
<b>NJM79L12S</b>						
Output Voltage	$V_O$	$V_{IN} = -19 \text{ V}$ , $I_O = 40 \text{ mA}$	-11.5	-12.0	-12.5	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -14.5 \text{ V to } -27 \text{ V}$ , $I_O = 40 \text{ mA}$	-	36	170	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -19 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	16	85	mV
Quiescent Current	$I_Q$	$V_{IN} = -19 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.5	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -15 \text{ V to } -25 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{PP}$ , $f = 120 \text{ Hz}$	37	67	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -19 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	290	-	$\mu\text{V}$

## ■ ELECTRICAL CHARACTERISTICS (continued)

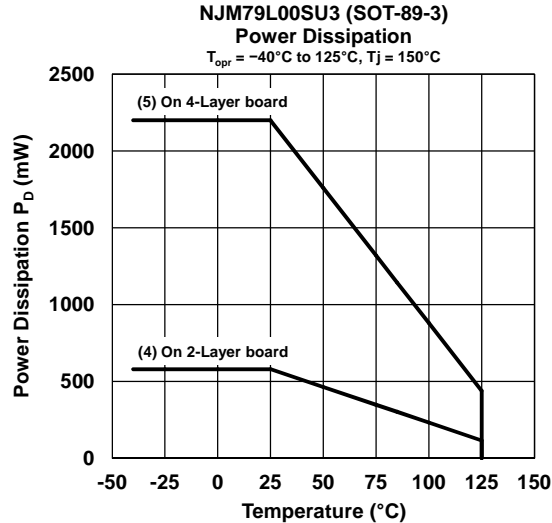
$C_{IN} = 0.33 \mu\text{F}$ ,  $C_O = 1.0 \mu\text{F}$ ,  $T_J = 25^\circ\text{C}$ , unless otherwise noted.

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>NJM79L15S</b>						
Output Voltage	$V_O$	$V_{IN} = -23 \text{ V}$ , $I_O = 40 \text{ mA}$	-14.4	-15.0	-15.6	V
Line Regulation	$\Delta V_O - V_{IN}$	$V_{IN} = -17.5 \text{ V to } -30 \text{ V}$ , $I_O = 40 \text{ mA}$	-	45	200	mV
Load Regulation	$\Delta V_O - I_O$	$V_{IN} = -23 \text{ V}$ , $I_O = 1 \text{ mA to } 100 \text{ mA}$	-	20	125	mV
Quiescent Current	$I_Q$	$V_{IN} = -23 \text{ V}$ , $I_O = 0 \text{ mA}$	-	3.5	6.5	mA
Dropout Voltage	$\Delta V_{IO}$	$I_O = 100 \text{ mA}$	-	1.6	2.0	V
Ripple Rejection	RR	$V_{IN} = -18.5 \text{ V to } -28.5 \text{ V}$ , $I_O = 40 \text{ mA}$ , $e_{in} = 1 \text{ V}_{P-P}$ , $f = 120 \text{ Hz}$	34	64	-	dB
Output Noise Voltage	$V_{NO}$	$V_{IN} = -23 \text{ V}$ , $BW = 10 \text{ Hz to } 100 \text{ kHz}$ , $I_O = 40 \text{ mA}$	-	340	-	$\mu\text{V}$

## ■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
Junction-to-Ambient Thermal Resistance SOT-89-3	$\theta_{ja}$	2-Layer <sup>(4)</sup> / 4-Layer <sup>(5)</sup> 215 / 58	$^\circ\text{C/W}$
Junction-to-Top of Package Characterization Parameter SOT-89-3	$\Psi_{jt}$	2-Layer <sup>(4)</sup> / 4-Layer <sup>(5)</sup> 40 / 19	$^\circ\text{C/W}$

## ■ POWER DISSIPATION vs. AMBIENT TEMPERATURE

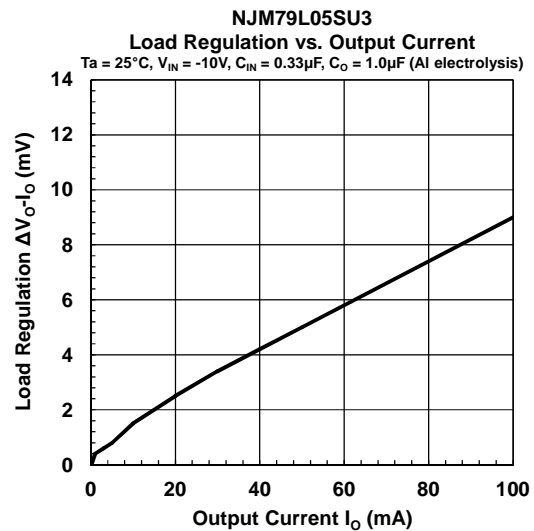
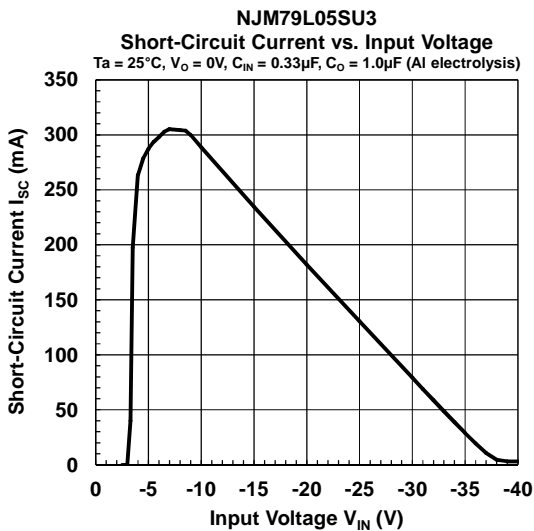
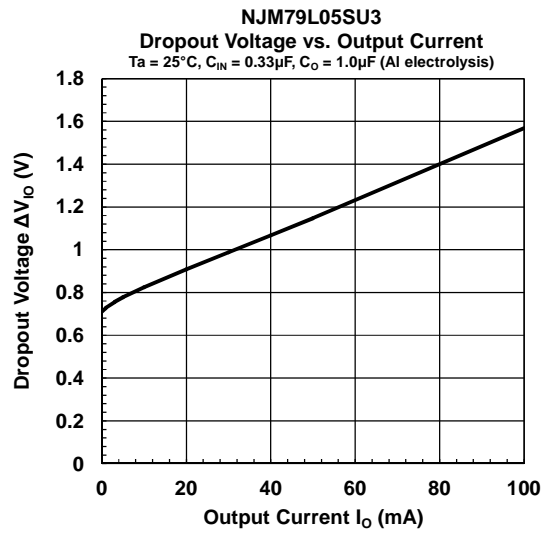
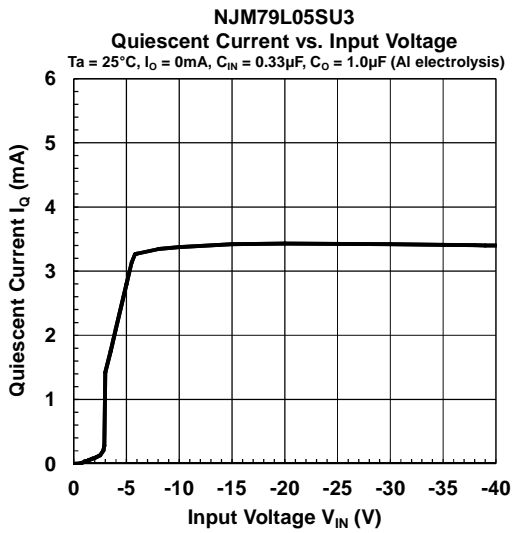
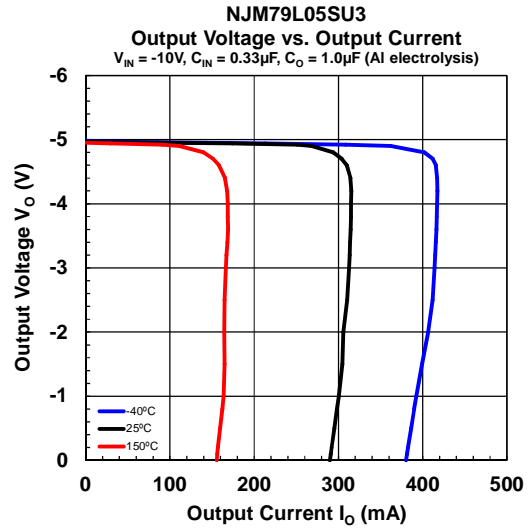
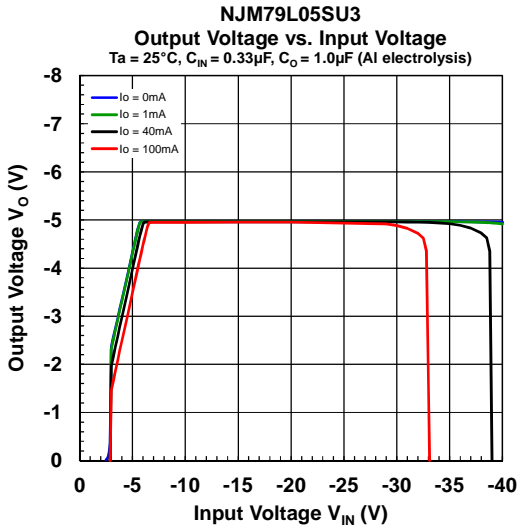


(4) 2-Layer: Mounted on glass epoxy board (76.2 mm × 114.3 mm × 1.6 mm: based on EIA/JEDEC standard, 2-layer FR-4).

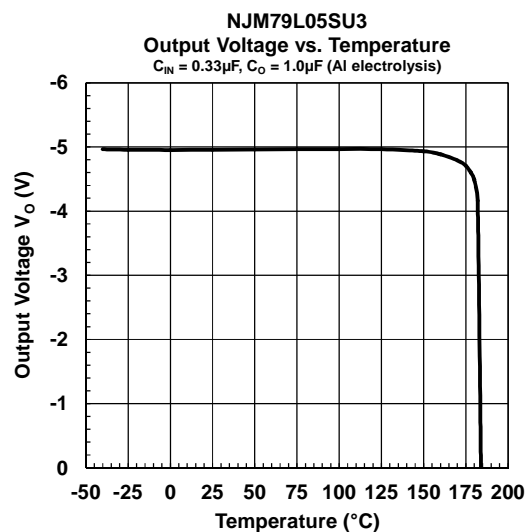
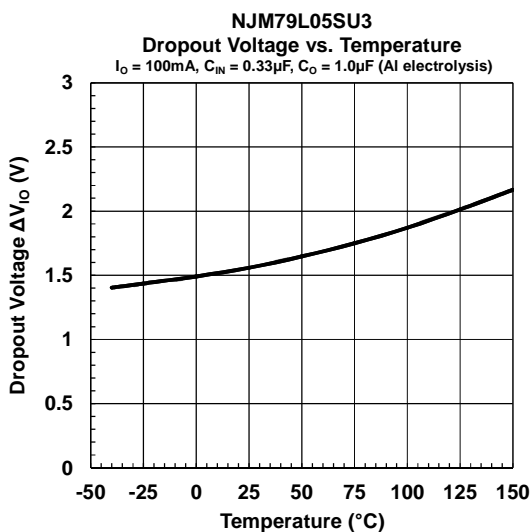
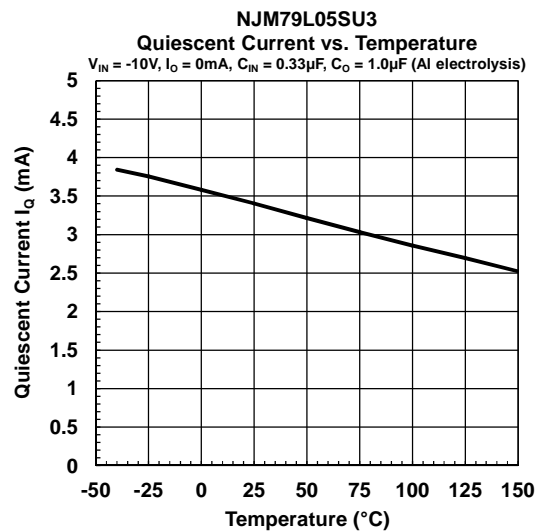
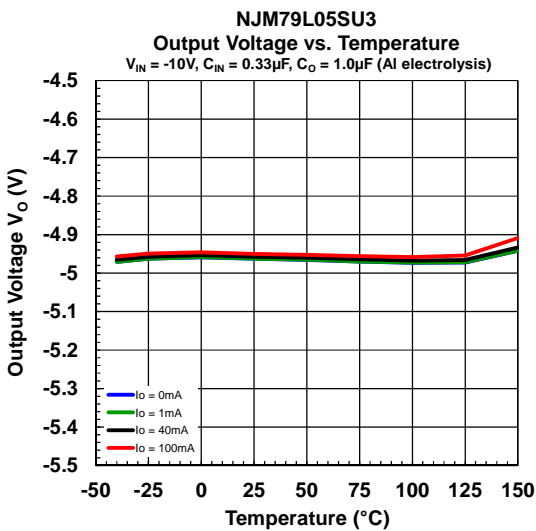
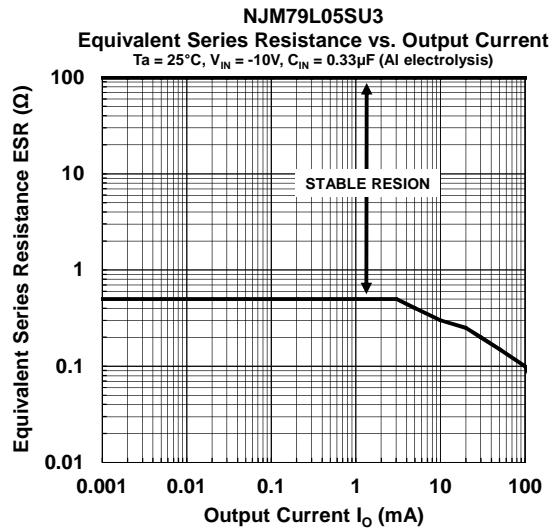
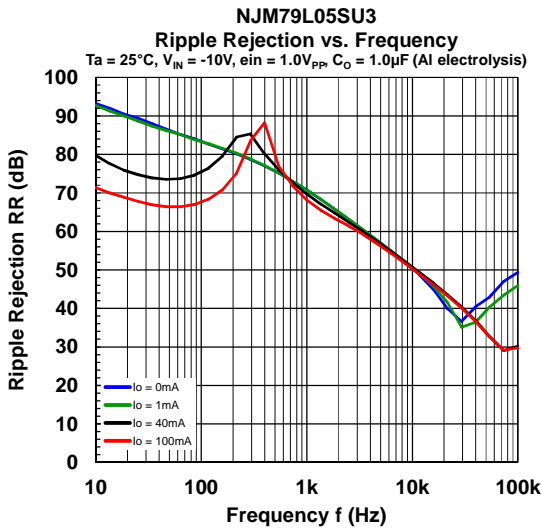
(5) 4-Layer: Mounted on glass epoxy board (76.2 mm × 114.3 mm × 1.6 mm: based on EIA/JEDEC standard, 4-layer FR-4).

(For 4-layer: Applying 74.2 mm × 74.2 mm inner Cu area and a thermal via hole to a board based on JEDEC standard JESD51-5.)

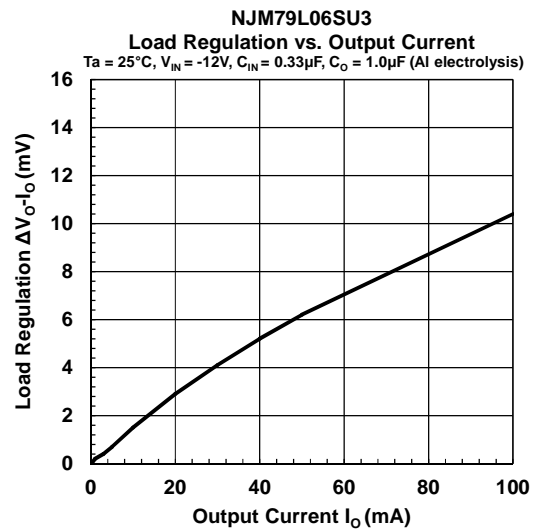
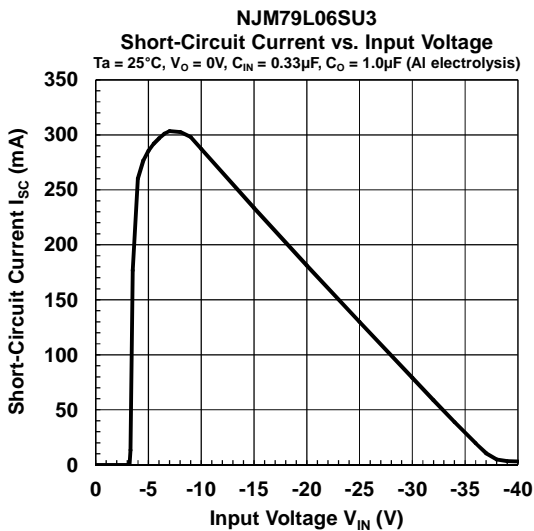
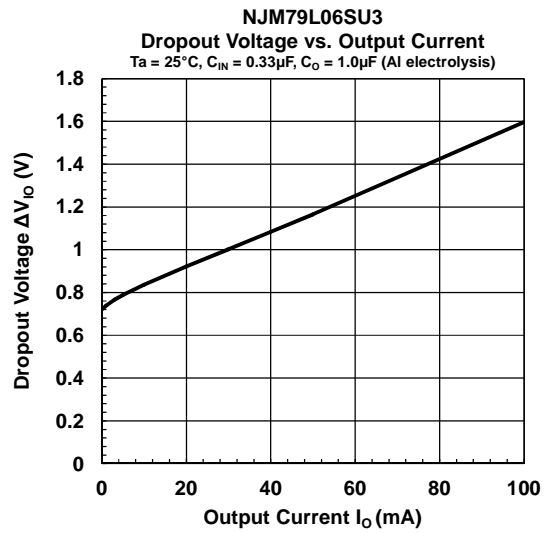
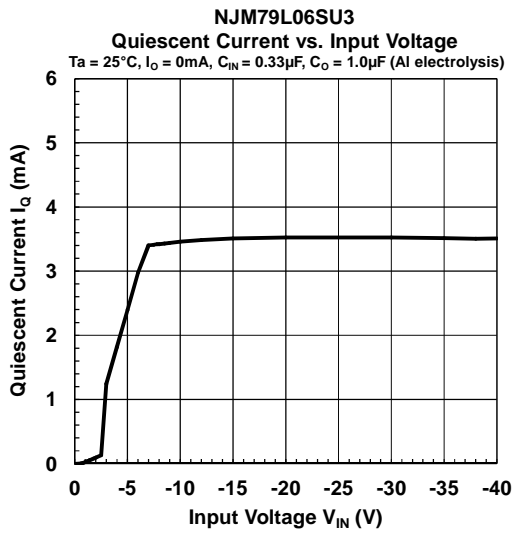
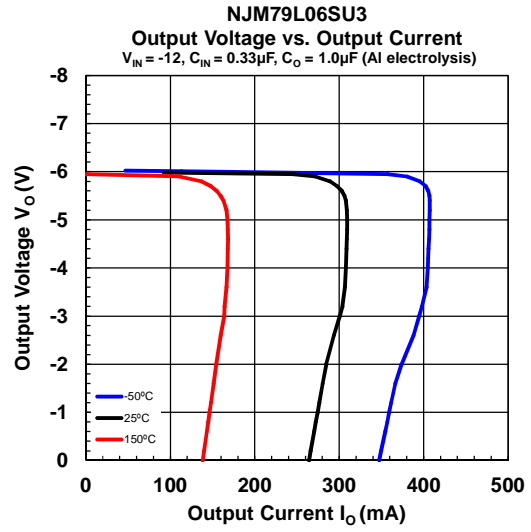
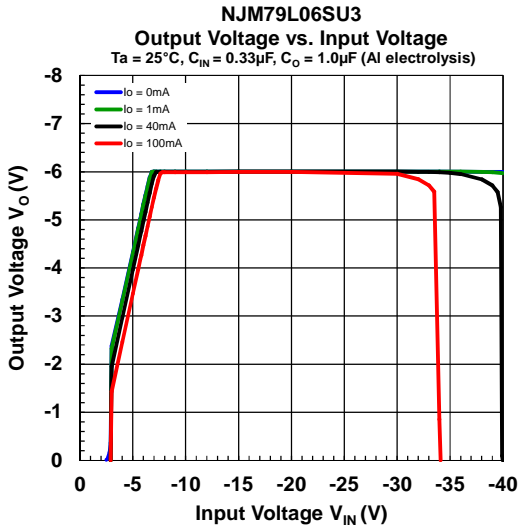
## ■ -5V TYPICAL CHARACTERISTICS



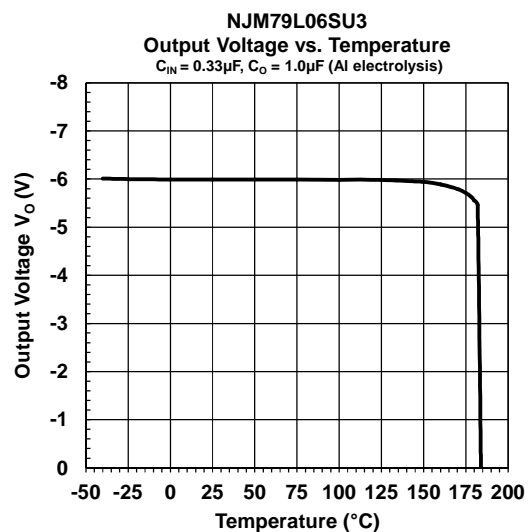
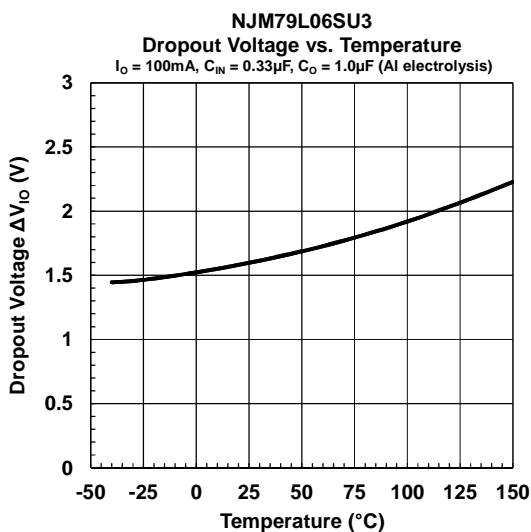
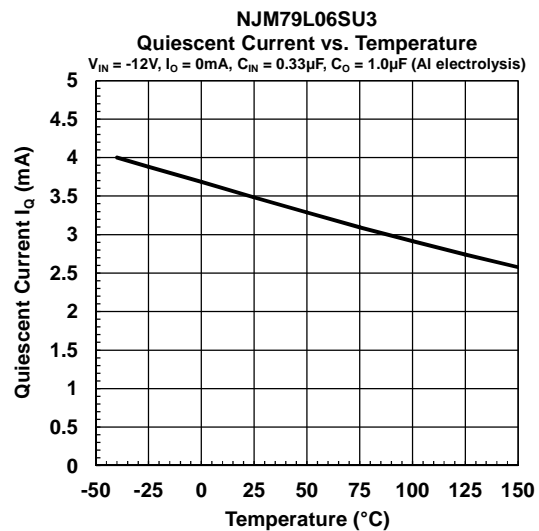
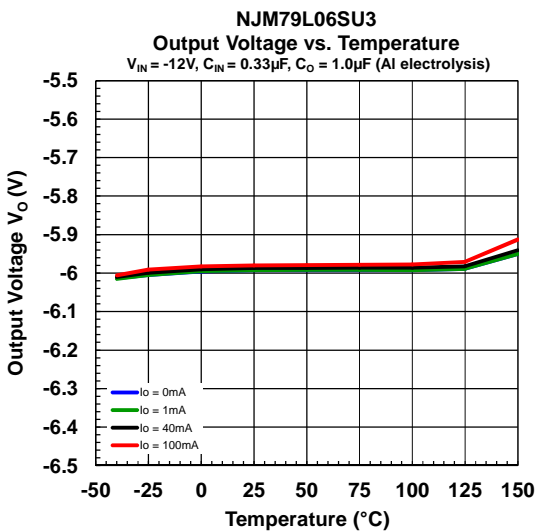
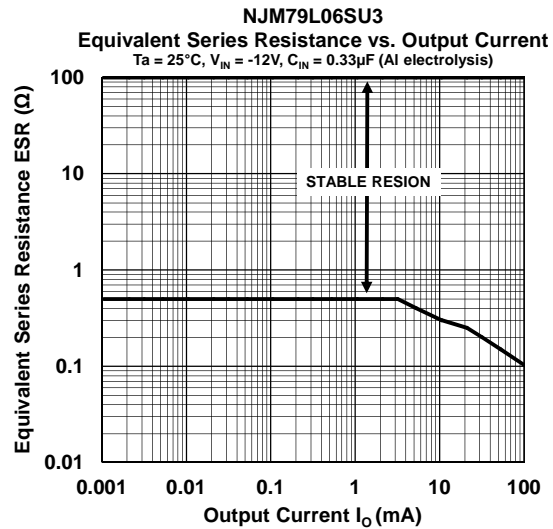
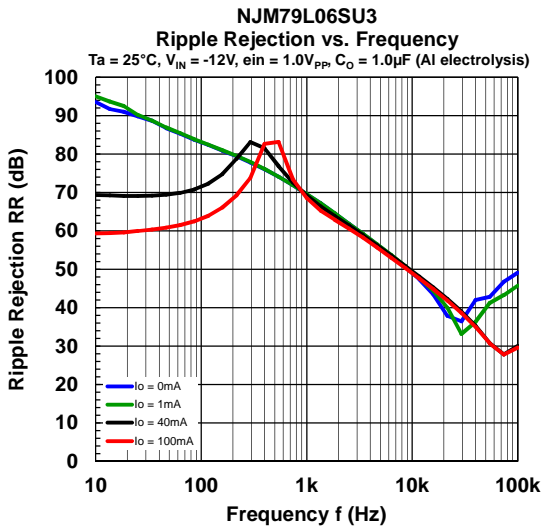
## ■ -5V TYPICAL CHARACTERISTICS



## ■ -6V TYPICAL CHARACTERISTICS

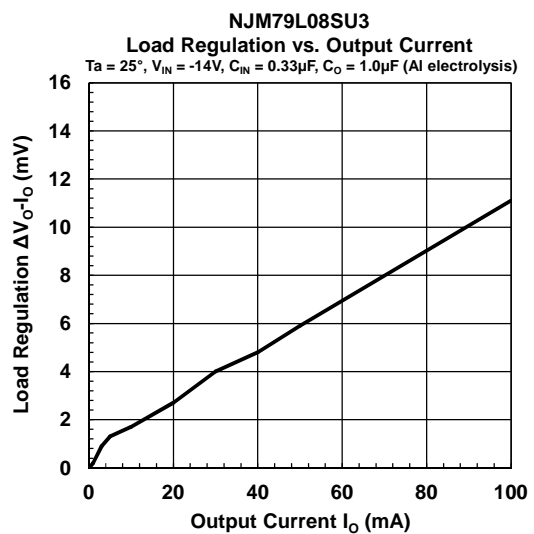
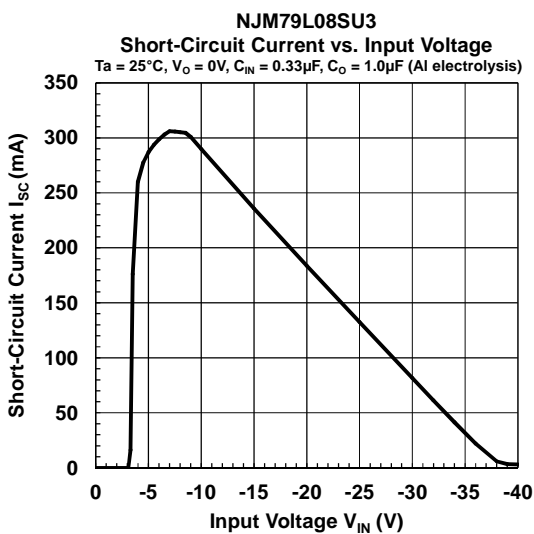
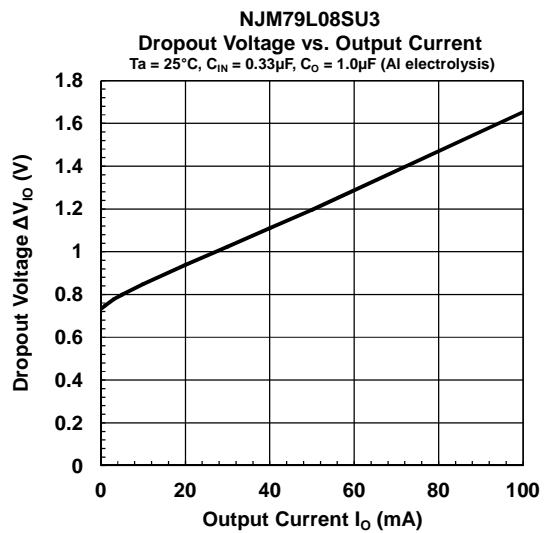
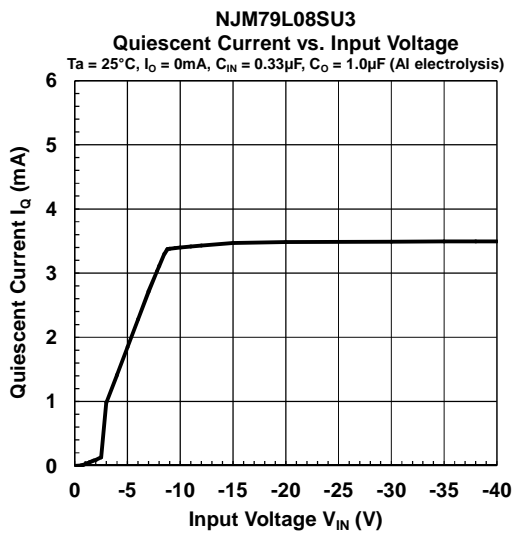
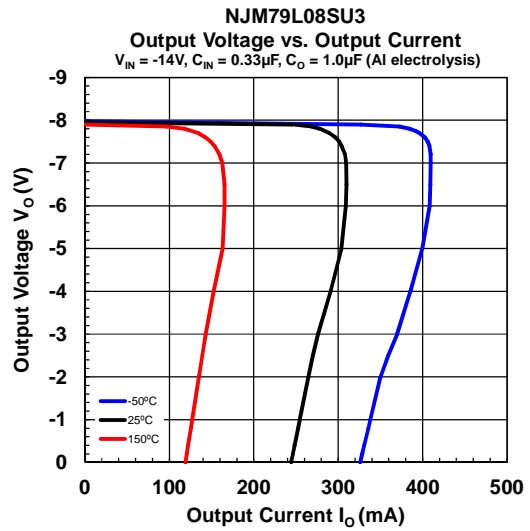
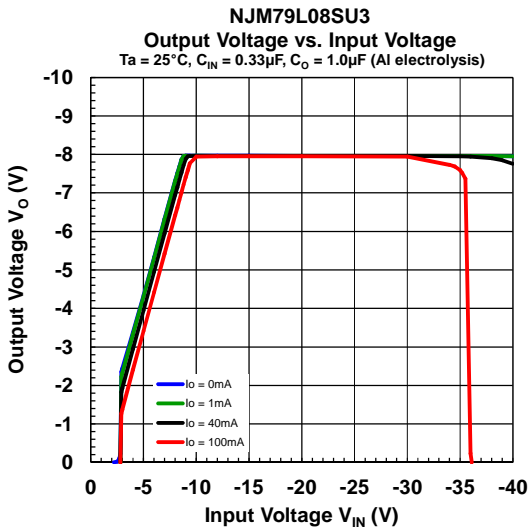


## ■ -6V TYPICAL CHARACTERISTICS

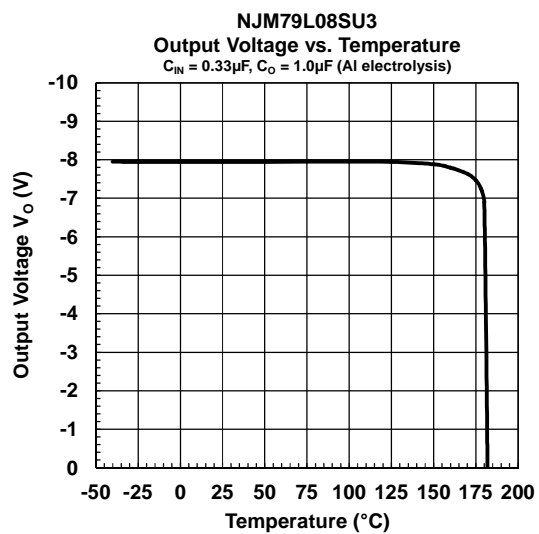
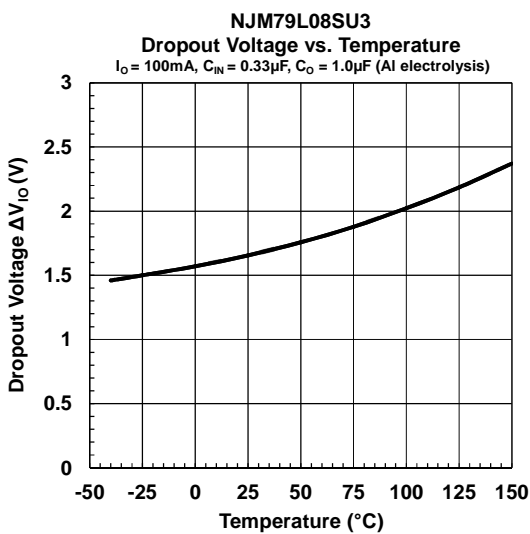
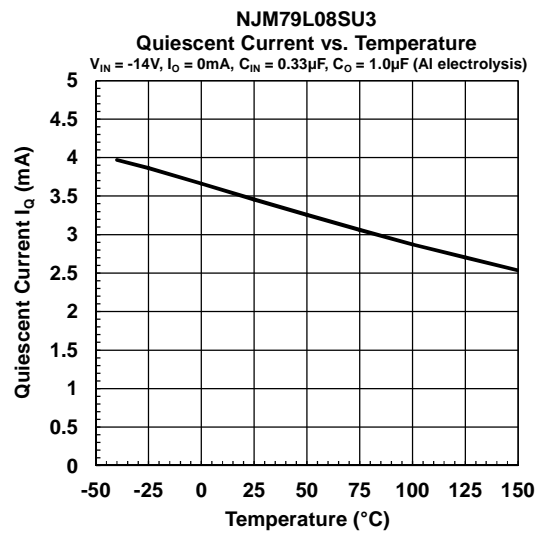
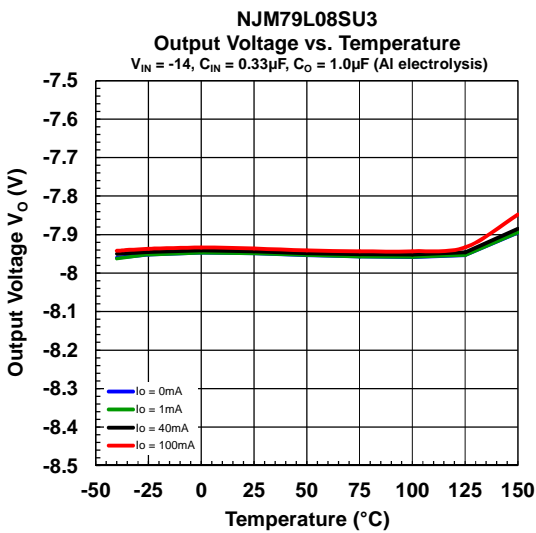
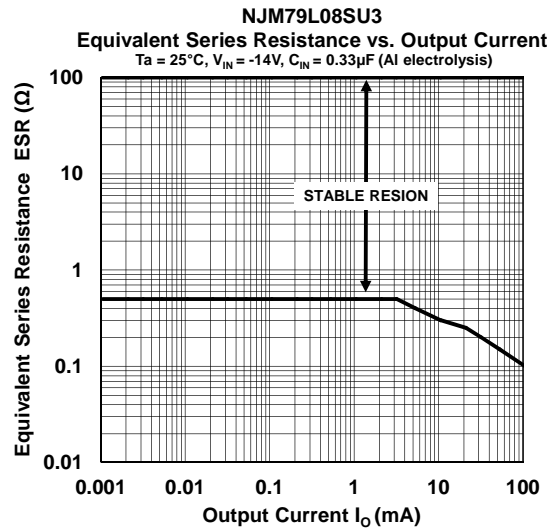
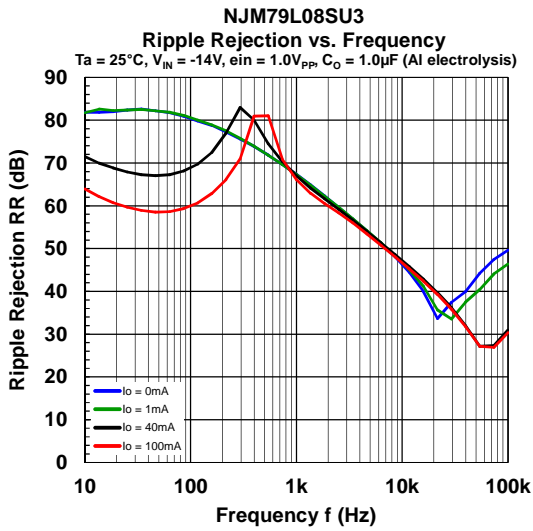




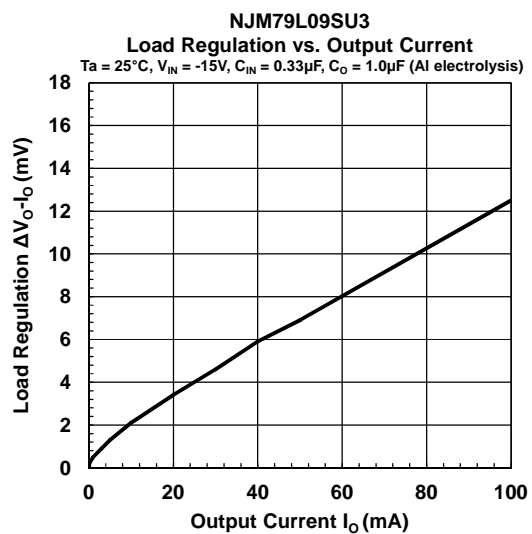
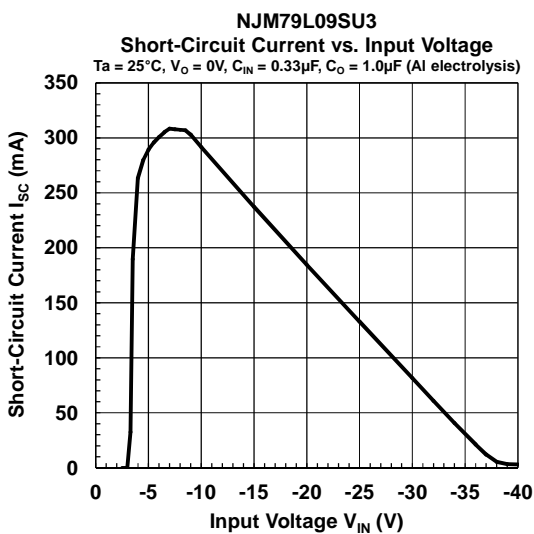
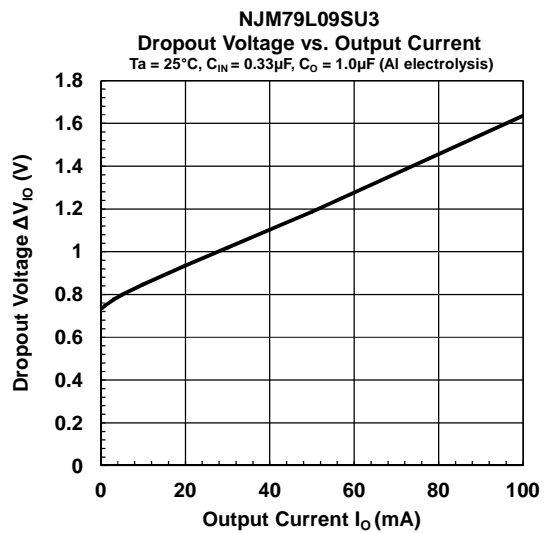
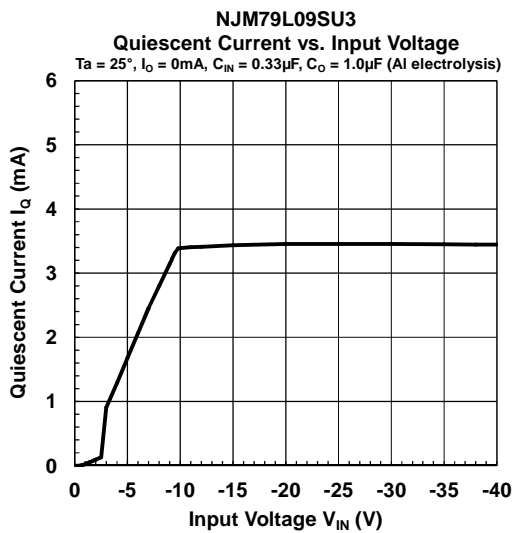
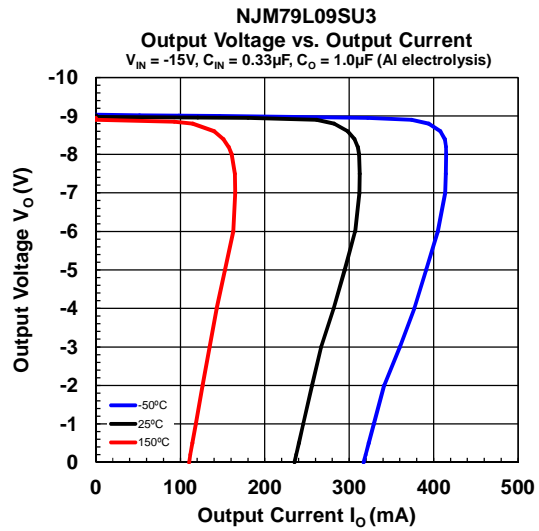
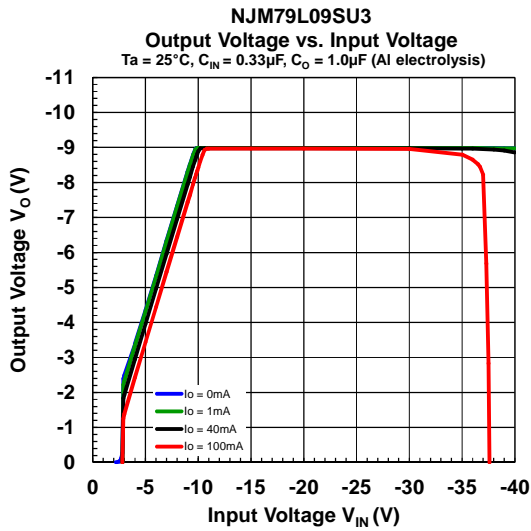
## ■ -8V TYPICAL CHARACTERISTICS



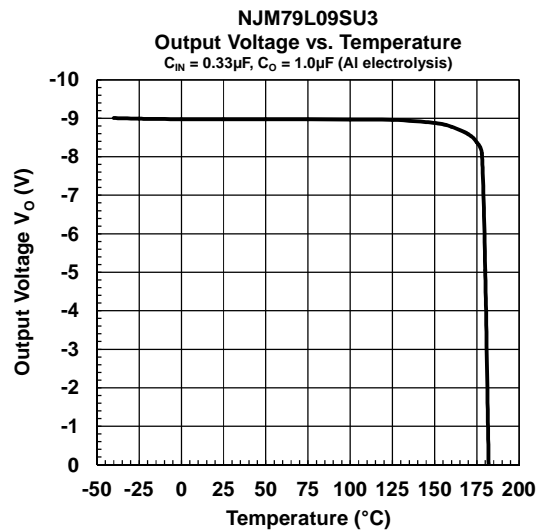
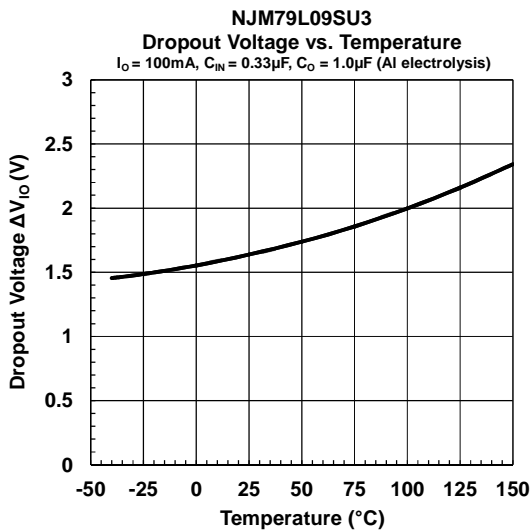
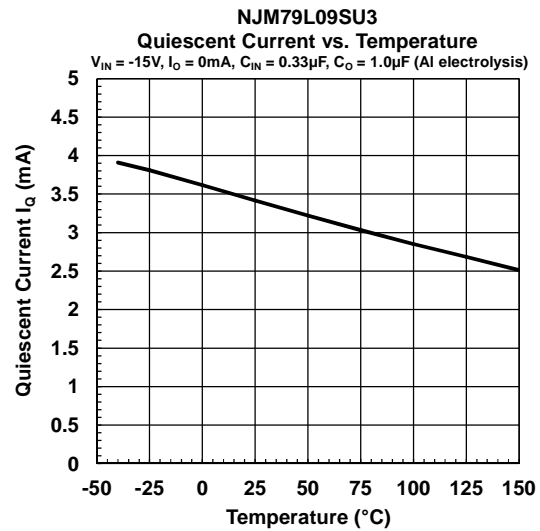
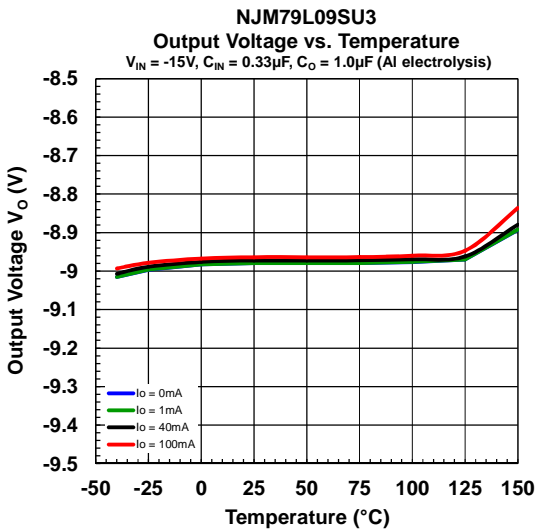
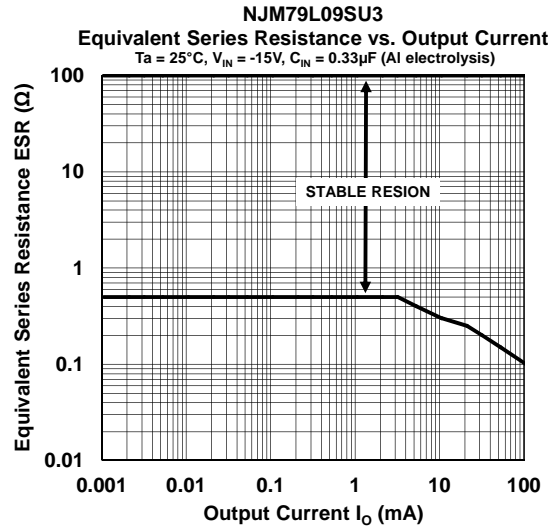
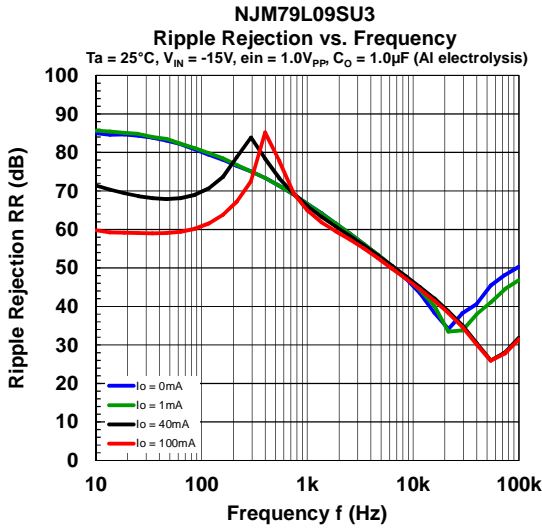
## ■ -8V TYPICAL CHARACTERISTICS



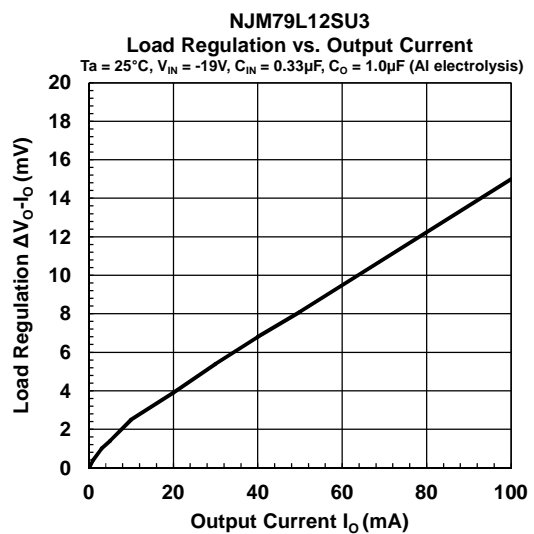
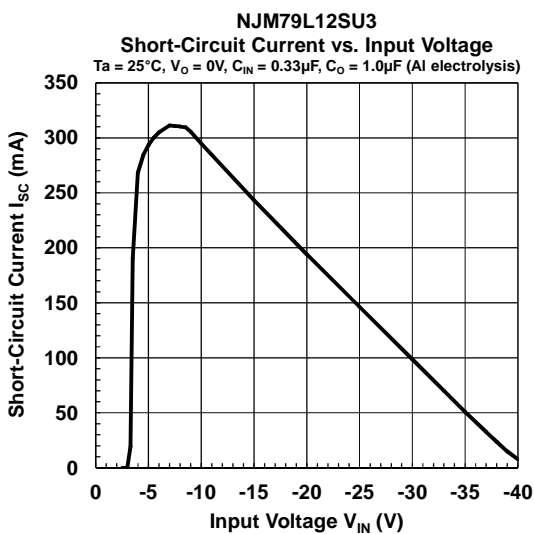
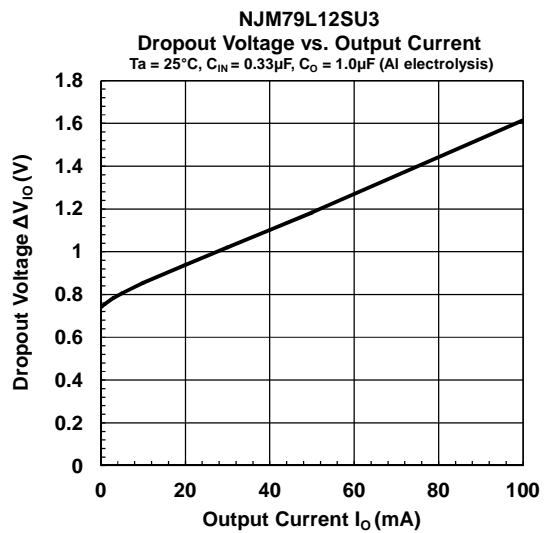
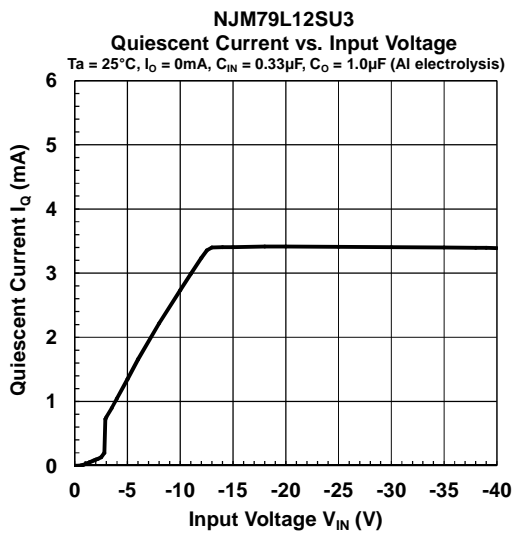
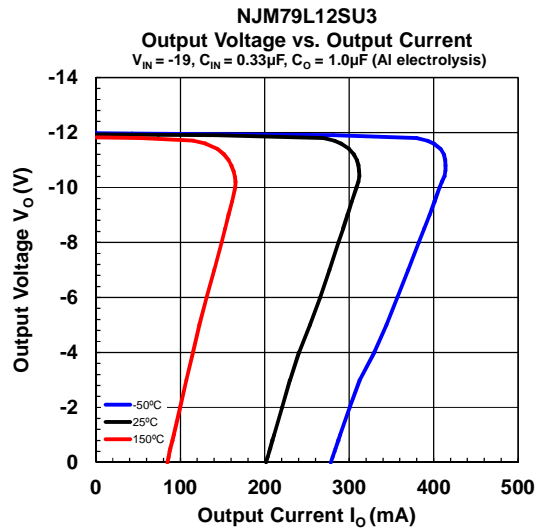
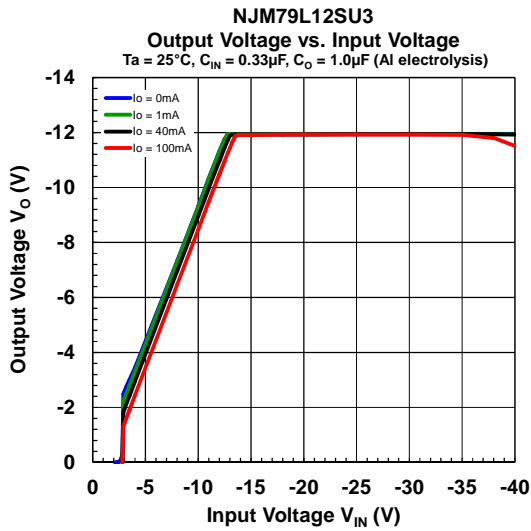
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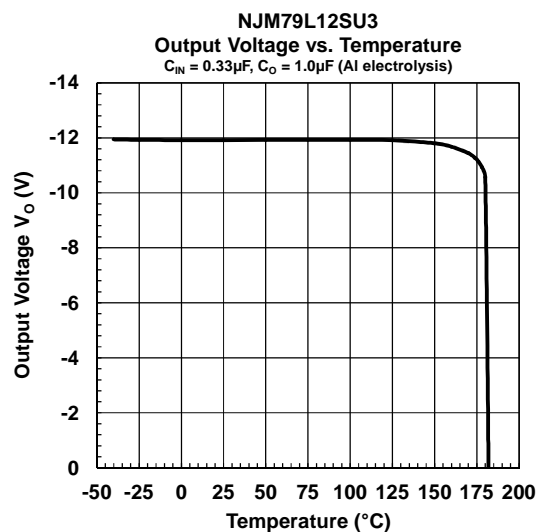
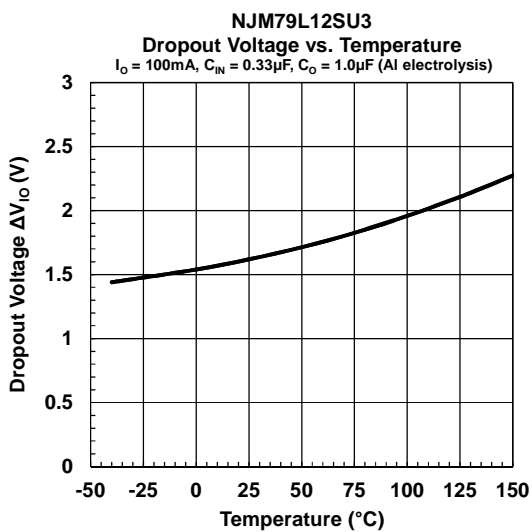
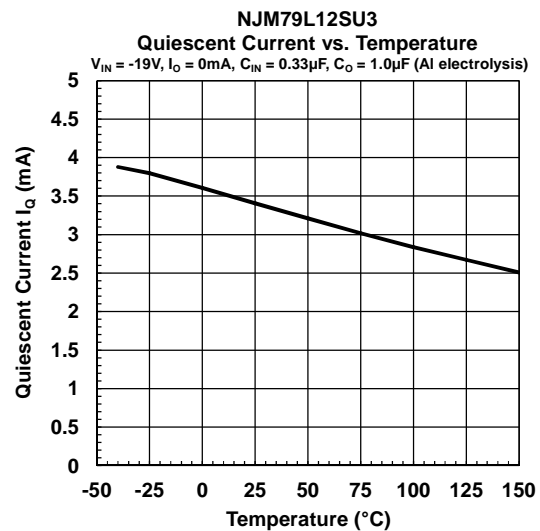
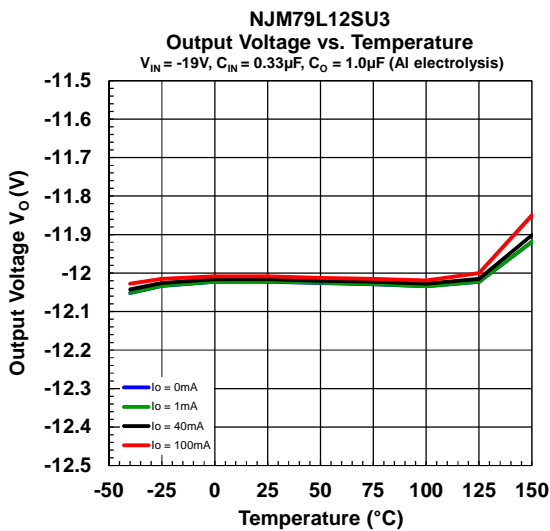
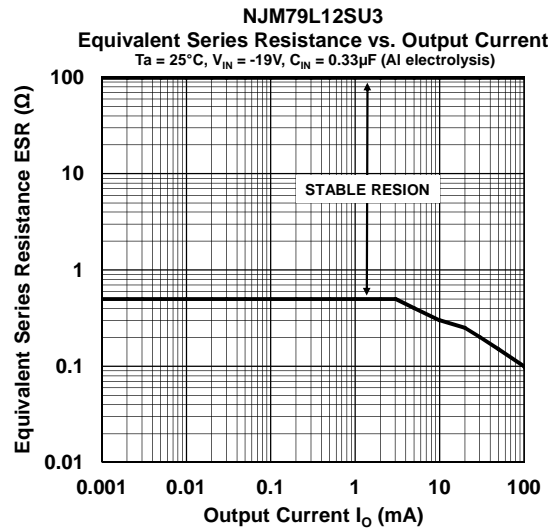
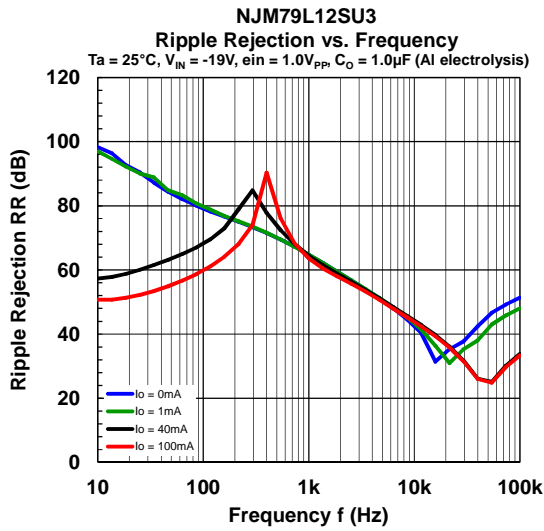
## ■ -9V TYPICAL CHARACTERISTICS



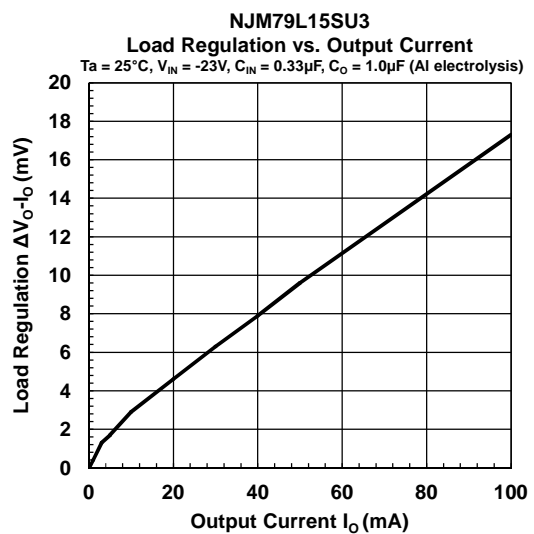
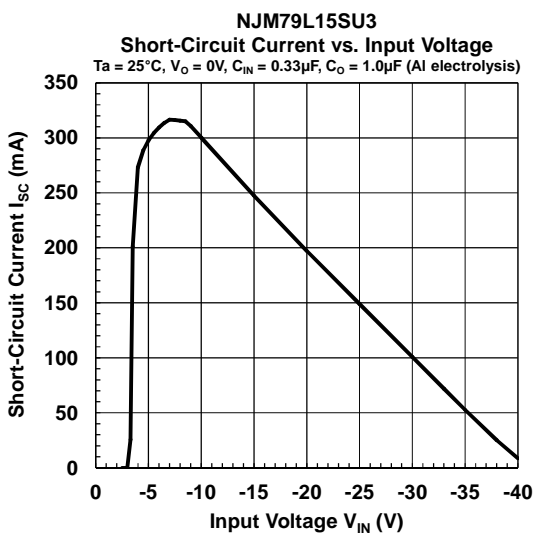
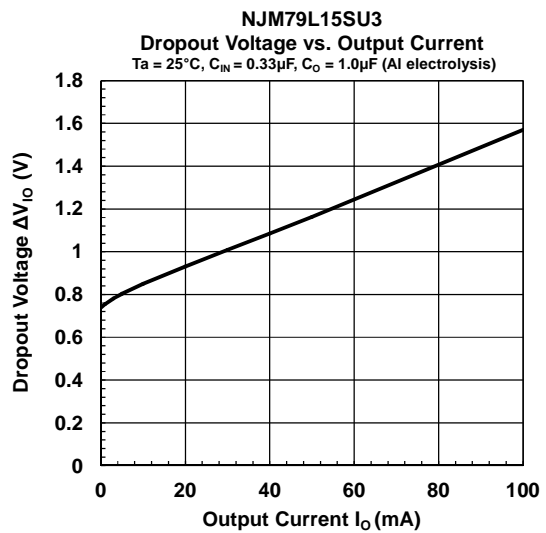
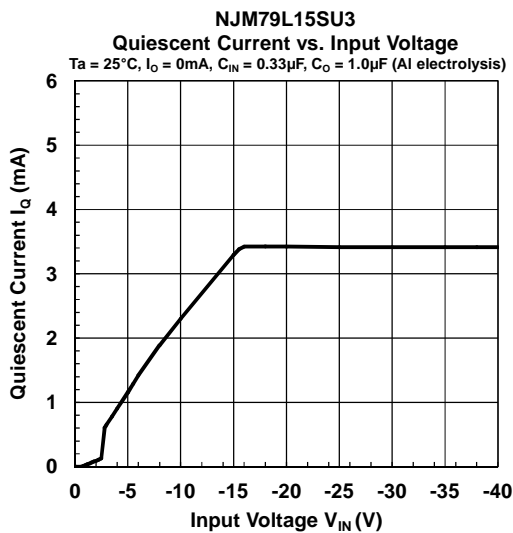
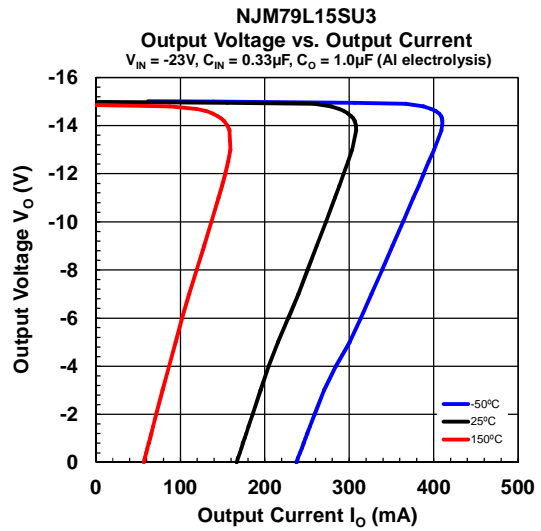
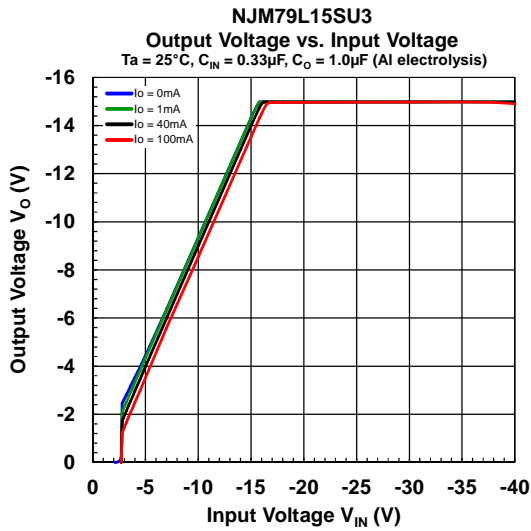
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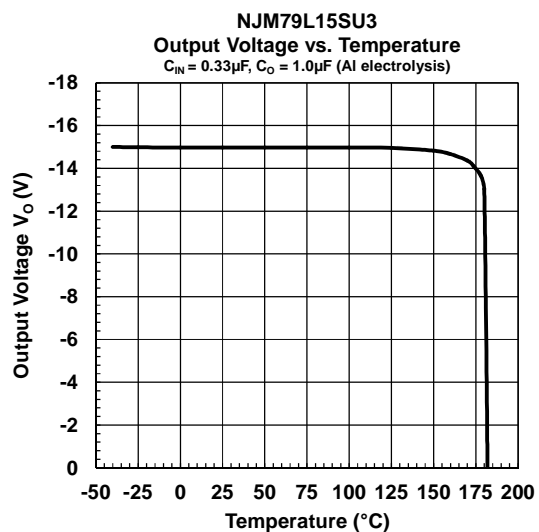
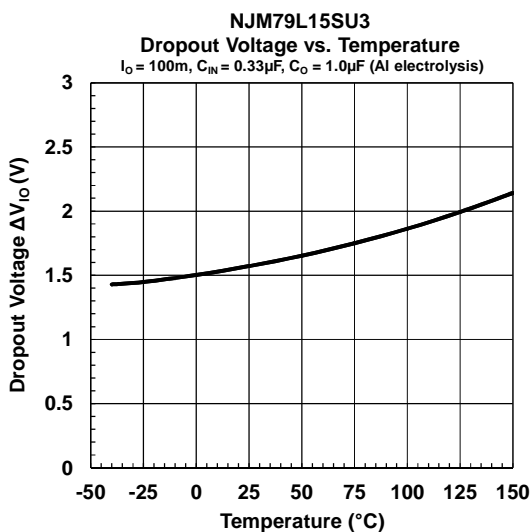
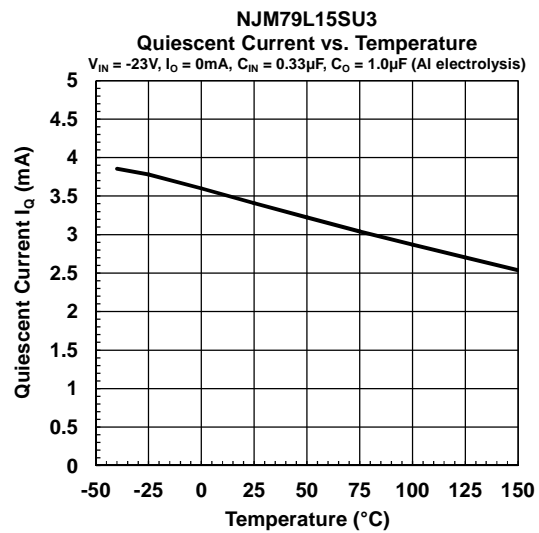
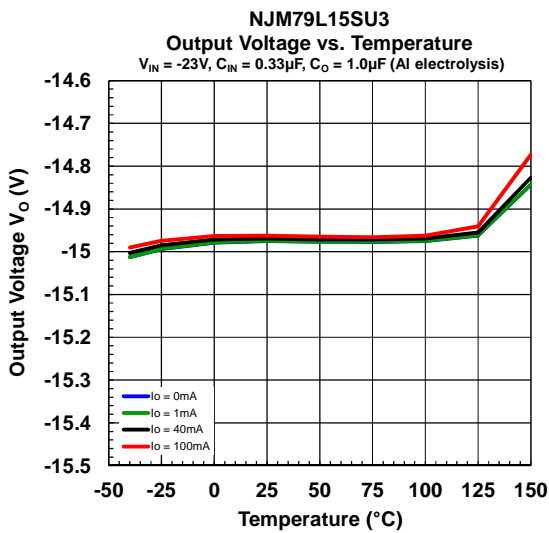
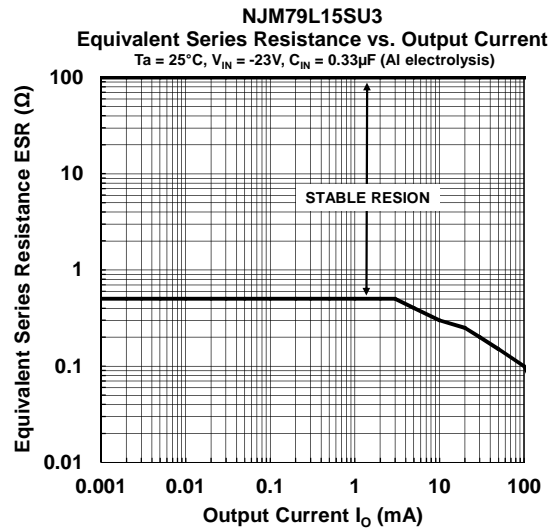
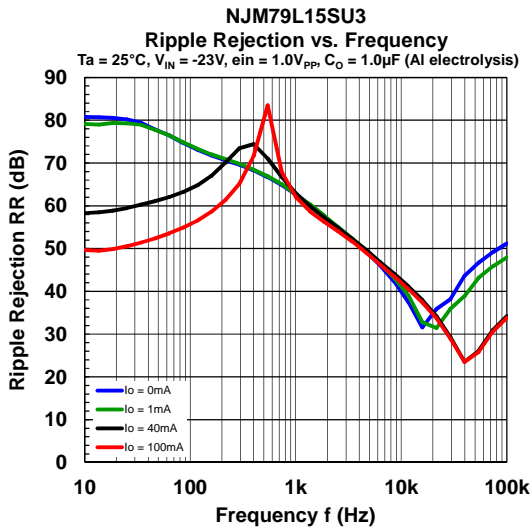
## ■ -12V TYPICAL CHARACTERISTICS



## ■ -15V TYPICAL CHARACTERISTICS



## ■ -15V TYPICAL CHARACTERISTICS





**■ APPLICATION NOTE / GLOSSARY****Input Capacitor ( $C_{IN}$ )**

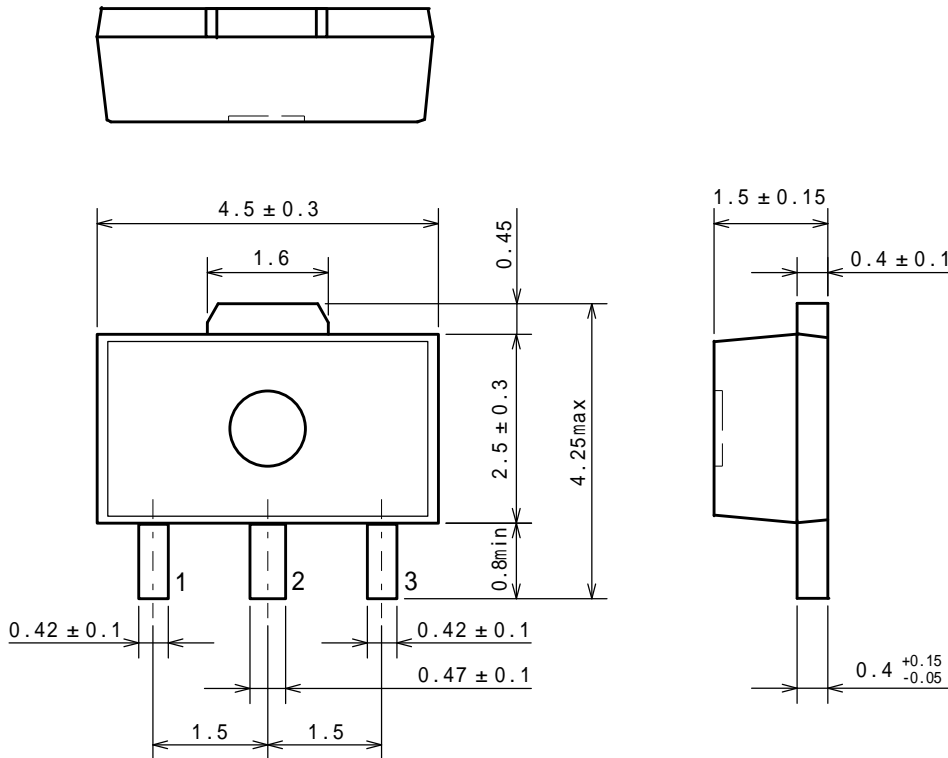
The  $C_{IN}$  prevents oscillations and reduce power supply ripple of applications when the power supply impedance is high or power supply line is long. Connecting a 0.33  $\mu$ F or larger  $C_{IN}$  between  $V_{IN}$  and GND pins as short path as possible.

**Output Capacitor ( $C_O$ )**

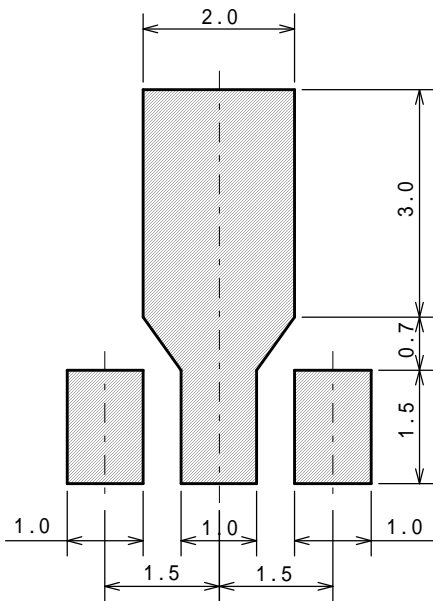
$C_O$  is necessary for phase compensation of the error amplifier built in the regulator, and the capacitance value and ESR (Equivalent Series Resistance) affect the stability of the circuit. If a  $C_O$  with a capacitance value of less than 1.0  $\mu$ F or a  $C_O$  with an ESR characteristic outside the stable area is used, output noise and/or regulator oscillation may occur due to lack of the phase compensation. For stable operation, connect a 1.0  $\mu$ F or larger aluminum electrolytic capacitor with ESR characteristics within the stable operation area between the  $V_{OUT}$  and GND pins as short path as possible. As the capacitance value of  $C_O$  increases, output noise and ripple decrease, and the response to output load fluctuations also improves.

Select the output capacitor considering various characteristics such as frequency characteristics, temperature characteristics, and DC bias characteristics. For the  $C_O$ , a capacitor with excellent temperature characteristics and sufficient margin for output voltage is recommended.

### ■ PACKAGE DIMENSIONS

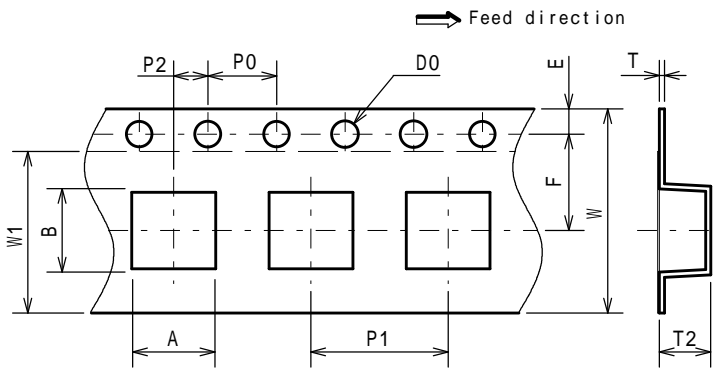


### ■ EXAMPLE OF SOLDER PADS DIMENSIONS



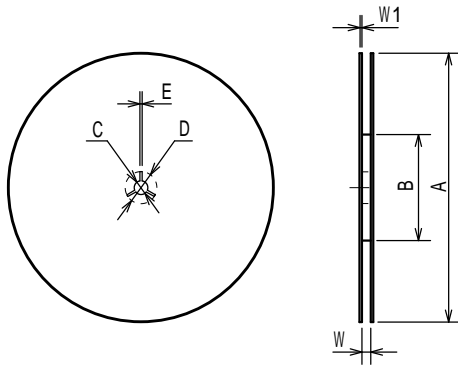
### PACKING SPEC

#### TAPING DIMENSIONS



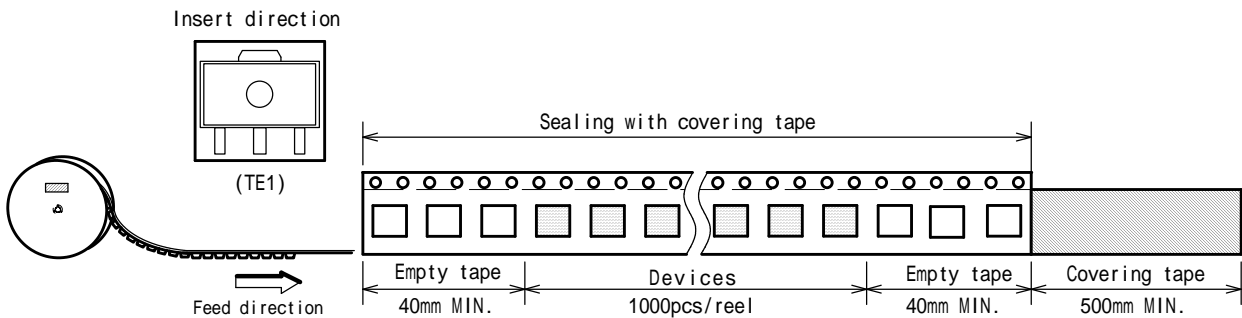
SYMBOL	DIMENSION	REMARKS
A	4.9 ± 0.1	BOTTOM DIMENSION
B	4.5 ± 0.1	BOTTOM DIMENSION
D0	1.5 <sup>+0.1</sup> <sub>0</sub>	
E	1.5 ± 0.1	
F	5.65 ± 0.1	
P0	4.0 ± 0.1	
P1	8.0 ± 0.1	
P2	2.0 ± 0.05	
T	0.3 ± 0.05	
T2	2.0	
W	12.0 ± 0.3	
W1	9.5	THICKNESS 0.1MAX

#### REEL DIMENSIONS

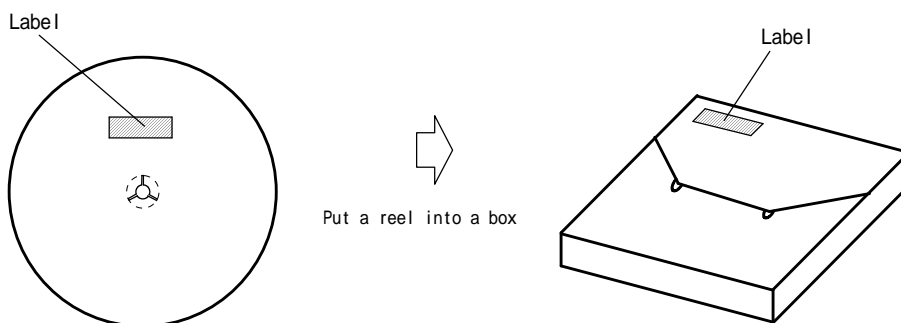


SYMBOL	DIMENSION
A	180 ± 1
B	60 ± 1
C	13 ± 0.2
D	21 ± 0.8
E	2 ± 0.5
W	13 ± 0.5
W1	1.2 ± 0.2

#### TAPING STATE

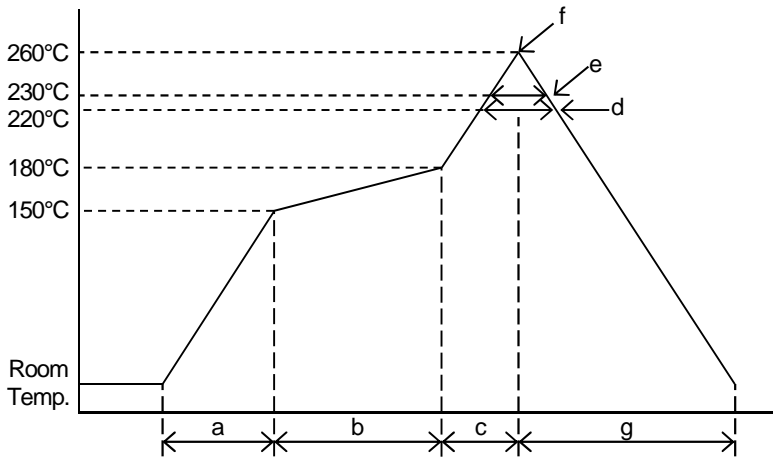


#### PACKING STATE



## ■ RECOMMENDED MOUNTING METHOD

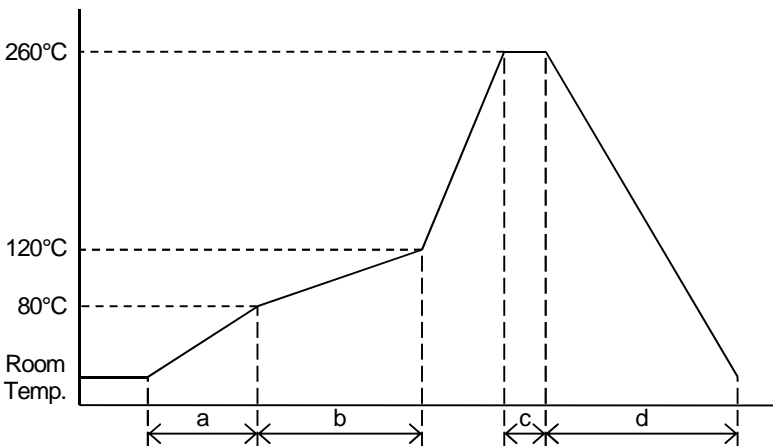
### INFRARED REFLOW SOLDERING PROFILE



a	Temperature ramping rate	1 to 4°C/s
b	Pre-heating temperature	150 to 180°C
	Pre-heating time	60 to 120s
c	Temperature ramp rate	1 to 4°C/s
d	220°C or higher time	shorter than 60s
e	230°C or higher time	shorter than 40s
f	Peak temperature	lower than 260°C
g	Temperature ramping rate	1 to 6°C/s

The temperature indicates at the surface of mold package.

### FLOW SOLDERING PROFILE



a	Temperature ramping rate	1 to 7°C/s
b	Pre-heating temperature	80 to 120°C
	Pre-heating time	60 to 120s
c	Peak temperature	lower than 260°C
	Peak time	shorter than 10s
d	Temperature ramping rate	1 to 7°C/s

The temperature indicates at the surface of mold package.

## ■ REVISION HISTORY

DATE	REVISION	CHANGES
December 20, 2019	Ver.1.0	Initial release

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